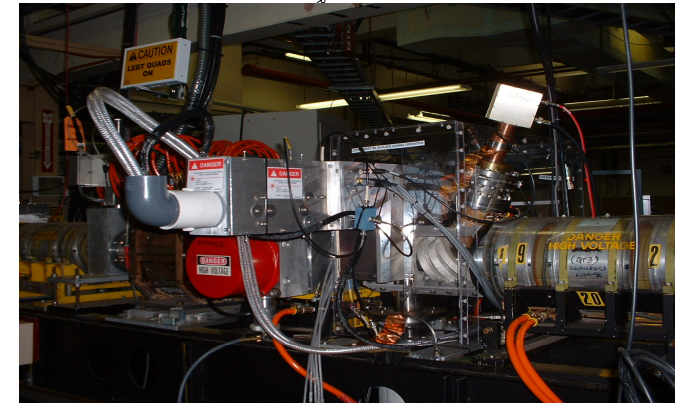
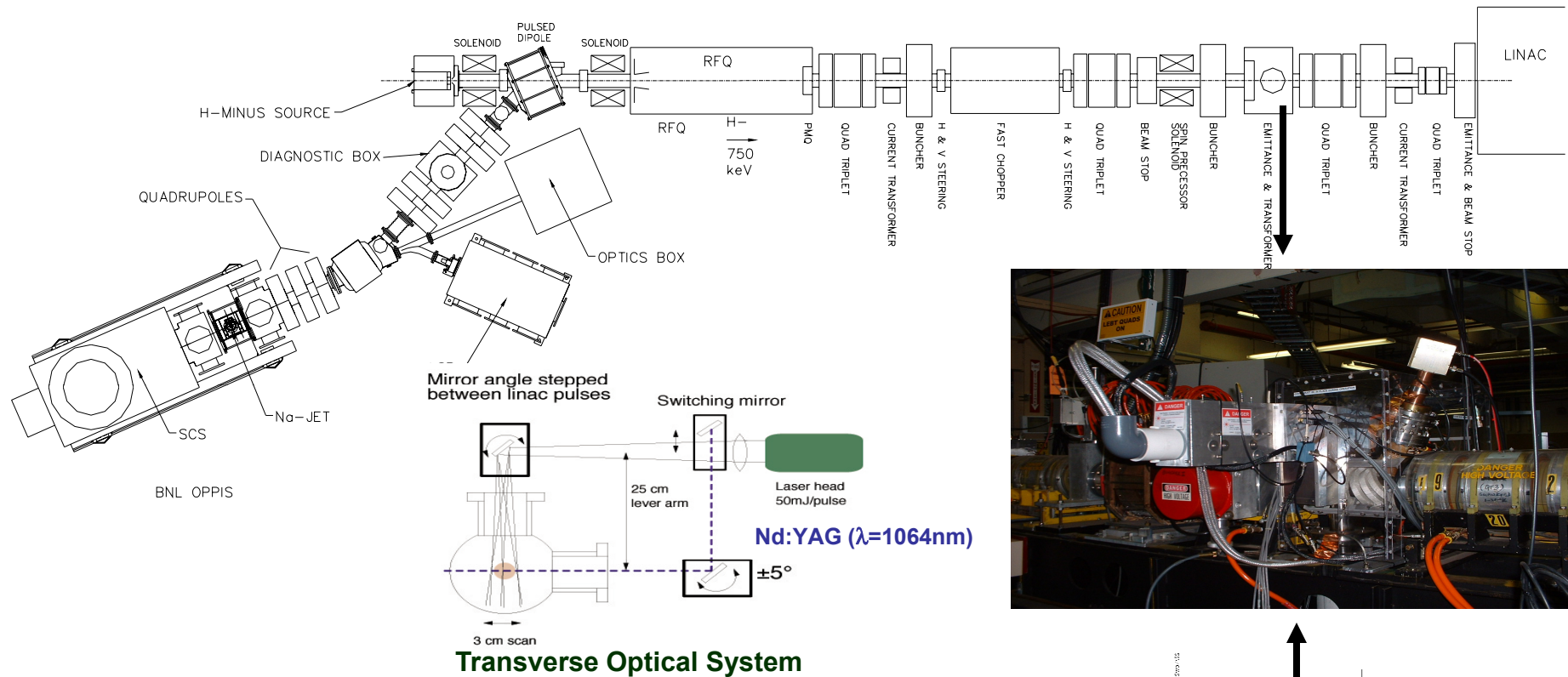


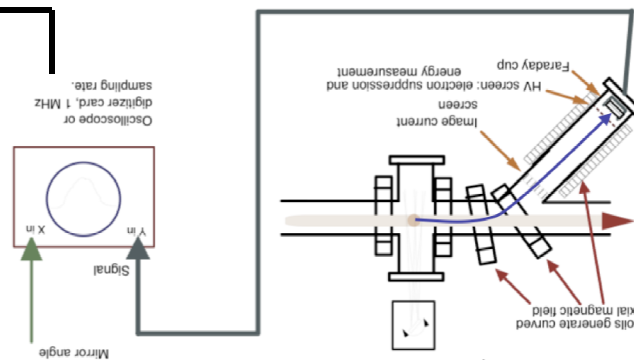
LASER BASED PROFILE AND ENERGY MONITOR DEVELOPMENT FOR H- BEAMS

R. Connolly, S. Bellavia, C. Dawson, C. Degen,
W. Meng, D. Raparia, T. Russo and N. Tsoupas
Brookhaven National Lab
Upton, NY, USA

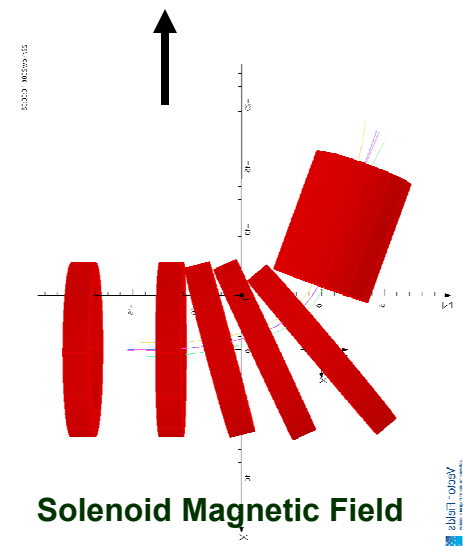
Profile Measurement



H- Beam profile



e from H- are guided by magnetic field



SC Potential Measurement

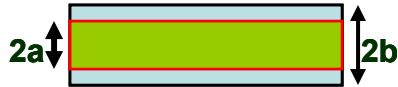
DC beam

$$V(r) = V_s(1 + 2\ln(b/a) - r^2/a^2); r \leq a$$

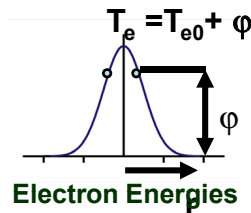
$$V(r) = 2V_s \ln(b/r); a \leq r \leq b$$

$$V_0 = V_s(1 + 2\ln(b/a))$$

$$V_s = 30 * I / \beta$$



I Cur. in Amp
β Rel. Parameter



$$T_{e0} = T_H / 1838 = 408 \text{ eV}$$

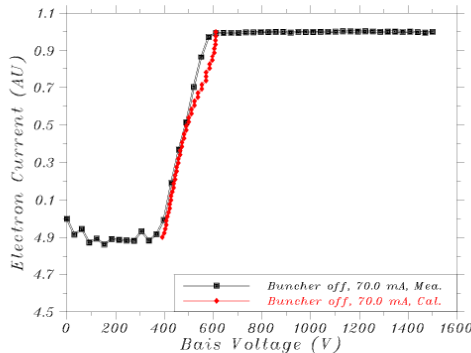
$$a_x = 13.5, a_y = 7.0 \text{ mm,}$$

$$b_x = b_y = 38 \text{ mm}$$

$$r = (x+y)/2 = 10.25 \text{ mm}$$

$$V_0(70\text{mA}) \sim 200 \text{ V}$$

$$E_e = 408 + 200 \sim 608 \text{ eV}$$



Electron Current VS Bias Voltage

$$E_H = 750,000 \text{ eV}$$

$$\Delta E_H = \pm 20,000 \text{ eV}$$

$$E_e = 408 \text{ eV}$$

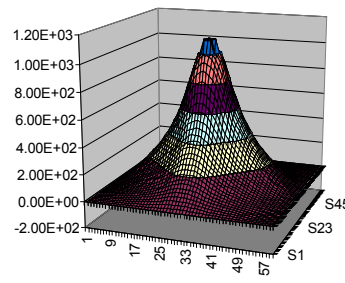
$$\Delta E_e = \pm 10.9 \text{ eV}$$

$$E_x = \frac{1}{4\pi\epsilon_0} \frac{3I\lambda}{c\gamma^2} \frac{(1-f)}{a_x(a_x+a_y)a_z} x$$

$$E_y = \frac{1}{4\pi\epsilon_0} \frac{3I\lambda}{c\gamma^2} \frac{(1-f)}{a_y(a_x+a_y)a_z} y$$

$$E_z = \frac{1}{4\pi\epsilon_0} \frac{3I\lambda}{c} \frac{(1-f)}{a_x a_y a_z} z$$

Electric Field due to Uniformly Charged Ellipsoid



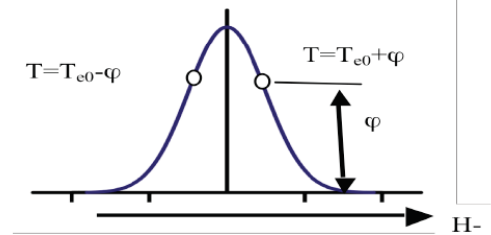
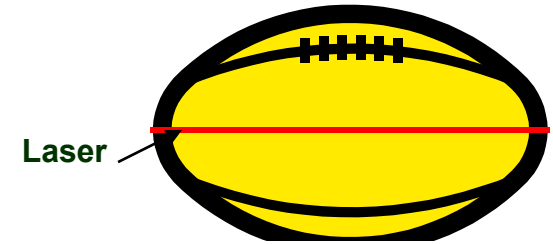
Potential Distribution in x-z Plane

Table I: Beam parameters used in the calculations

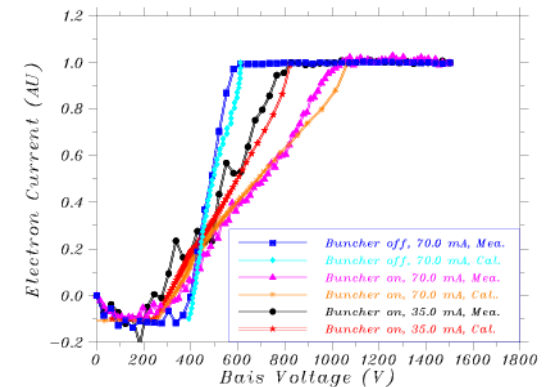
Current mA	Buncher On/off	% of DC component	Bunched Length degrees
70	OFF	100	360
70	ON	50	90
35	ON	30	70

Beam Parameters Used in Simulations

Bunched Beam



Electron Energies



Electron Current VS Bias Voltage

Summary

- Transverse Profile
- At low energies ($\Delta E(m_e/m_p) \ll \text{SCP}$)
 - Space Charge Potential (SCP)
 - Bunch Length and Bunching Factor
- At high ($\Delta E(m_e/m_p) \gg \text{SCP}$)
 - Energy Spread (ΔE)